









PRODUCT DATASHEET



- ► DC-In Solid State Relay
- ► DIP7 Gullwing 400mil
- ► Random Phase TRIAC Output

TDRX223(M)-GV





TDRX223(M) Series

DESCRIPTION:





The TDRX223(M) series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a monolithic silicon random-phase photo TRIAC to drive a power TRIAC in a plastic DIP7 package with Gullwing lead forming option.

FEATURES:

- High isolation 5000Vrms
- DC input with TRIAC output
- Operating temperature range -40°C to +85°C
- **REACH & RoHS compliance**
- MSL class 1
- **Regulatory Approvals:**
 - UL UL1577
 - VDE EN60747-5-5 (VDE0884-5)
 - CQC GB4943.1, GB8898
 - cUL CSA Component Acceptance Service Notice 5A
- Packing: 45pcs/tube

APPLICATIONS:

- Solenoid/valve controls
- Lighting controls
- Motor controls
- Temperature controls
- Static AC power switches
- Solid state relays
- Interfacing microprocessors to 115 to 240VAC peripherals











Release Date: 24 June 2025 Version: A00



NAMING & ORDERING INFORMATION:

Naming Information:

| TDR X 223 (M) - G V | | |
|---------------------|---|--|
| TDRX223 | Part Number | |
| X | Selection: On-State RMS Current (X=0~3) | |
| M | Lead Form Option: DIP7 Gullwing | |
| G | Green Option | |
| V | VDE Option | |

Ordering Information:

TDR<u>X</u>223(M)-GV

 \underline{X} = Selection: On-State RMS Current (X=0~3)

| Part Number | Symbol | Values | | Unit | Tost Condition | |
|---------------|-----------------------|--------|------|------|----------------|--|
| Part Number | Symbol | Min. | Тур. | Max. | Unit | Test Condition |
| TDR0223(M)-GV | IT _(RMS) * | | | 0.3 | A | I _{TSM} =3A ** P _W =100μs, 120pps |
| TDR1223(M)-GV | | | | 0.6 | | I _{TSM} =6A P _W =100μs, 120pps |
| TDR2223(M)-GV | | | | 0.9 | | I _{TSM} =9A P _W =100μs, 120pps |
| TDR3223(M)-GV | | | | 1.2 | | I _{TSM} =12A Pw=100μs, 120pps |

^{*} $IT_{(RMS)}$ = On-State RMS Current

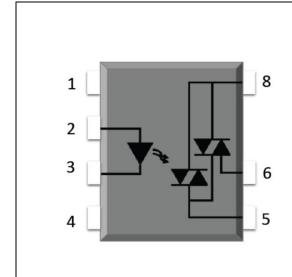
| Version No. | Original Release Date | | |
|-------------|-----------------------|--|--|
| Rev: A00 | 29/08/2024 | | |

^{**} I_{TSM} = Non-repetitive Surge Current



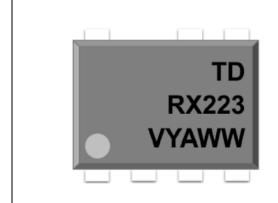
SCHEMATIC DIAGRAM & MARKING:

Schematic Diagram:



| PIN Definition | | | |
|----------------|----------|--|--|
| 1 | NC | | |
| 2 | Anode | | |
| 3 | Cathode | | |
| 4 | NC | | |
| 5 | Gate | | |
| 6 | Terminal | | |
| 7 | (Absent) | | |
| 8 | Terminal | | |

Marking Information:



| Marking Definition | | | |
|--------------------|--------------------|--|--|
| TD | Manufacturer Code | | |
| RX223 | Part Number | | |
| V | VDE Applicable | | |
| Υ | Fiscal Year | | |
| А | Manufacturing Code | | |
| ww | Work Week | | |

Labelling Information:



This product is manufactured, tested, and packed by



for more details, please visit www.tdled.com



ABSOLUTE CHARACTERISTICS:

Absolute Maximum Ratings:

| Parameter | | Symbol | Ratings | Unit | |
|----------------------------------|---------|-----------------------|------------------|------|--|
| | | INPUT | | | |
| Forward Current | | I _F | 60 | mA | |
| Peak Forward Current | | I _{FP} | 1 *1 | А | |
| Reverse Voltage | | V _R | 6 | V | |
| Junction Temperature | | Tj | 125 | °C | |
| Input Power Dissipation | | Pı | 100 | mW | |
| | (| OUTPUT | | | |
| Off-State Output Terminal Voltag | e | V _{DRM} | 600 | V | |
| | TDR0223 | | 0.3 | | |
| 0.01.000 | TDR1223 |] . | 0.6 | | |
| On-State RMS Current | TDR2223 | - I _{T(RMS)} | 0.9 | А | |
| | TDR3223 | | 1.2 | | |
| | TDR0223 | | 3 | | |
| Non-repetitive Surge Current | TDR1223 |] | 6 | А | |
| Pw=100μs, 120pps | TDR2223 | - I _{TSM} | 9 | | |
| | TDR3223 | | 12 | | |
| Junction Temperature | | Tj | 125 | °C | |
| | C | OMMON | | | |
| Total Power Dissipation | | P _{tot} | 400 | mW | |
| Isolation Voltage | | V _{iso} | 5000 *² | Vrms | |
| Operating Temperature | | T _{opr} | -40~+85 | °C | |
| Storage Temperature | | T _{stg} | -40~+125 | °C | |
| Soldering Temperature | | T _{sol} | 260 for 10s max. | °C | |

^{*1. 100}µs pulse, 100Hz frequency.

^{*2.} AC for 1 minute, R.H.= $40^{\circ}60\%$.



ELECTRICAL CHARACTERISTICS:

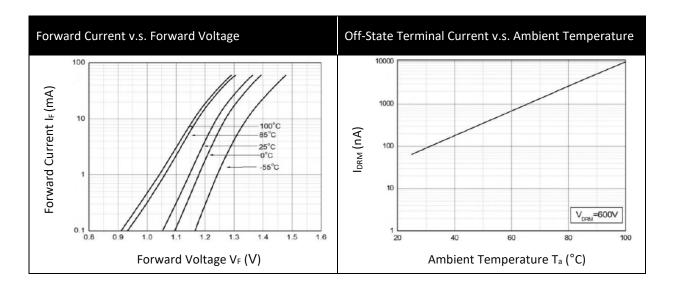
Electrical Optical Characteristics at T_a=25°C:

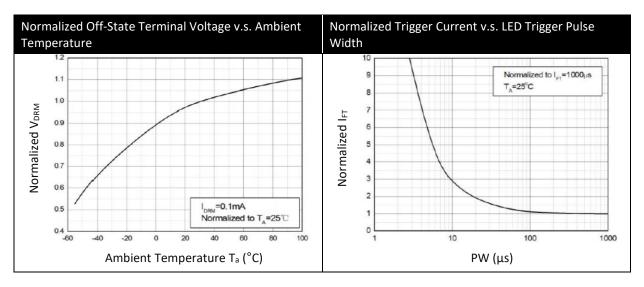
| Parameter | Symbol | | Values | | Unit | Test Condition |
|---|--------------------------|-------------------|--------|------|------|---|
| Parameter | Symbol | Min. | Тур. | Max. | Unit | rest Condition |
| | | INPU ⁻ | Γ | | | |
| Forward Voltage | V _F | | 1.24 | 1.4 | V | I _F =10mA |
| Reverse Current | I _R | | | 10 | μΑ | V _R =6V |
| Input Capacitance | Cin | | 30 | | pF | V=0, f=1kHz |
| | | OUTPL | JT | | | |
| Peak Off-State Current Either Direction | I _{DRM} | | | 100 | μΑ | V _{DRM} =600V I _F =0 |
| On-State Terminal Voltage | V _{TM} | | 0.8 | 2.5 | V | I _{TM} =Rated I _{TM} |
| Critical Rate of Rise of Off-State Voltage - Breakdown Voltage | dV/dt | 1000 | | | V | V _{PEAK} =600V *1 |
| | TRANSFER CHARACTERISTICS | | | | | |
| LED Trigger Current | I _{FT} | | | 10 | mA | R _L =100Ω Terminal Voltage=6V |
| Holding Current | lн | | | 25 | mA | |
| Isolation Resistance | R _{ISO} | 10^12 | 10^14 | | Ω | DC=500V, 40~60% R.H. |
| Floating Capacitance | Сю | | 0.25 | 1 | pF | V=0, f=1MHz |

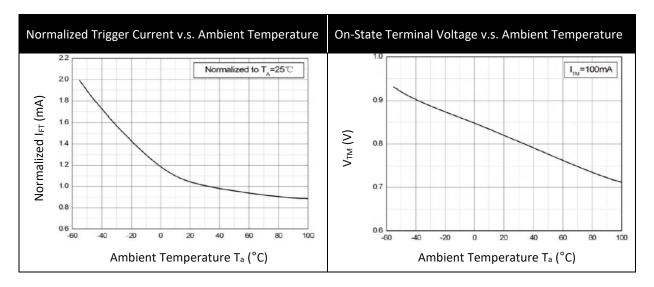
 $[{]m *1.}$ Test voltage must be applied within dV/dt rating.



CHARACTERISTIC CURVES:

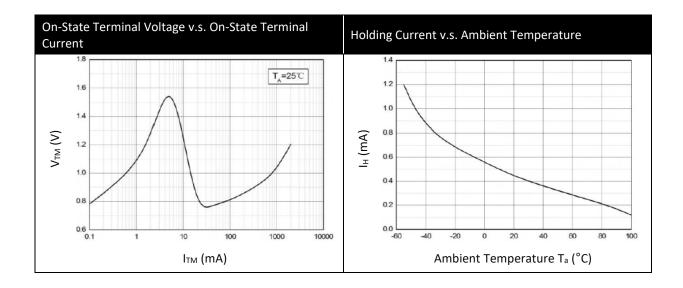


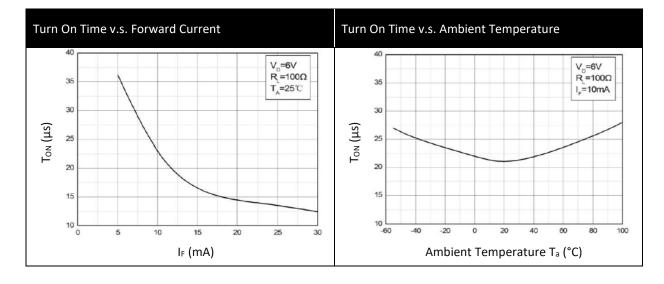






CHARACTERISTIC CURVES:

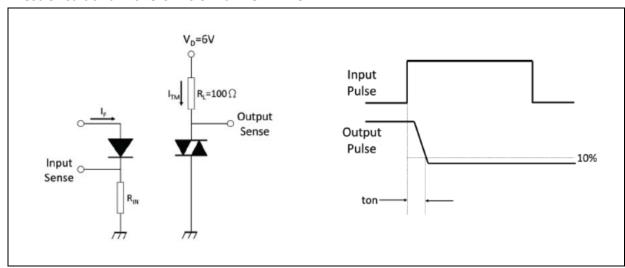




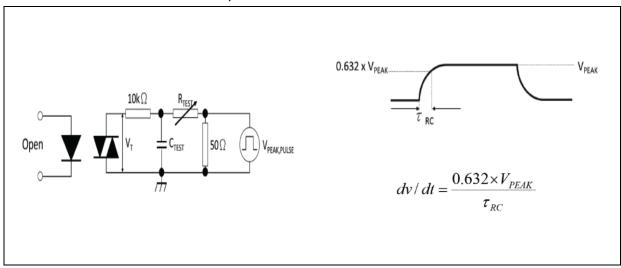


TEST CIRCUIT:

Test Circuit and Waveforms of Turn On Time:



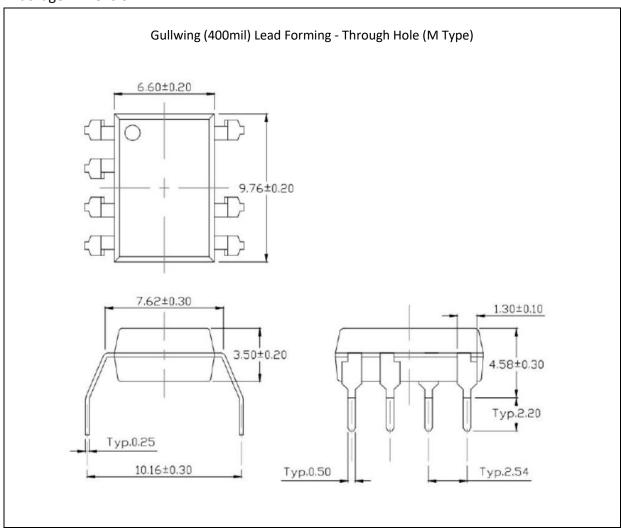
Test Circuit and Waveforms of dV/dt:





OUTLINE DIMENSION:

Package Dimension:

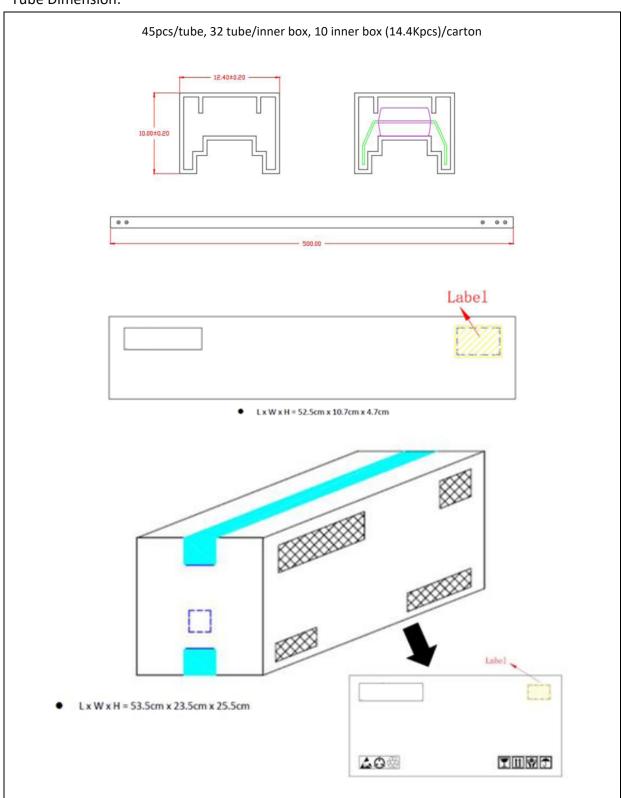


1. All dimensions are in millimetre (mm).



PACKING SPECIFICATION:

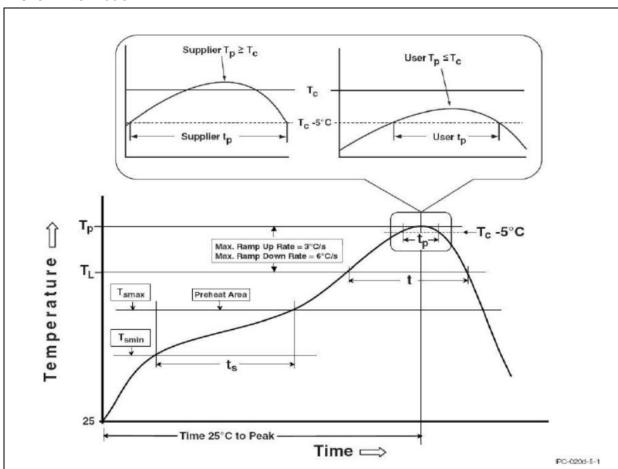
Tube Dimension:





RECOMMENDED SOLDERING PROFILE:

Reflow Information:

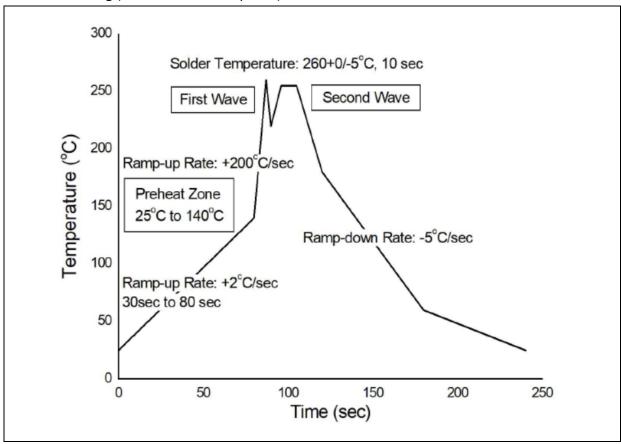


| Profile Feature | Sn-Pb Assembly Profile | Pb-Free Assembly Profile |
|---|------------------------|--------------------------|
| Temperature Min. (T _{smin}) | 100°C | 150°C |
| Temperature Max. (T _{smax}) | 150°C | 200°C |
| Time (t _s) from (T _{smin} to T _{smax}) | 60-120 seconds | 60-120 seconds |
| Ramp-up Rate (t∟ to t _P) | 3°C/second max. | 3°C/second max. |
| Liquidous Temperature (T _L) | 183°C | 217°C |
| Time (t _L) Maintained Above (T _L) | 60-150 seconds | 60-150 seconds |
| Peak Body Package Temperature | 235°C +0°C / -5°C | 260°C +0°C / -5°C |
| Time (t _P) within 5°C of 260°C | 20 seconds | 30 seconds |
| Ramp-down Rate (T _P to T _L) | 6°C/second max. | 6°C/second max. |
| Time 25°C to Peak Temperature | 6 minutes max. | 8 minutes max. |



RECOMMENDED SOLDERING PROFILE:

Wave Soldering (JESD22-A111 Compliant):



Hand Soldering:

| Soldering Temperature | 380±5°C |
|-----------------------|------------|
| Soldering Time | 3 sec max. |

Note:

- One time soldering is recommended for all soldering methods.
- Do not solder more than three times for IR reflow soldering.